



### **Schottky Barrier Rectifiers**

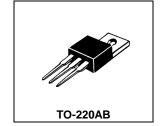
Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

- ¡ Low Forward Voltage.
- The Low Switching noise.
- i High Current Capacity
- i Guarantee Reverse Avalanche.
- i Guard-Ring for Stress Protection.
- i Low Power Loss & High efficiency.
- i 150¢J Operating Junction Temperature
- i Low Stored Charge Majority Carrier Conduction.
- 7 Plastic Material used Carries Underwriters Laboratory

Flammability Classification 94V-O

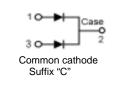
## SCHOTTKY BARRIER RECTIFIERS

6 AMPERES 30-45 VOLTS



# $\begin{array}{c|c} & & & & & & \\ & & & & & \\ \hline M & & & & & \\ \hline M & & & & & \\ \hline 1 & 2 & 3 & G \\ \hline 1 & 3 & 3 & G$

| DIM | MILLIMETERS |       |  |  |
|-----|-------------|-------|--|--|
|     | MIN         | MAX   |  |  |
| Α   | 14.68       | 15.32 |  |  |
| В   | 9.78        | 10.42 |  |  |
| С   | 5.02        | 6.52  |  |  |
| D   | 13.06       | 14.62 |  |  |
| Е   | 3.57        | 4.07  |  |  |
| F   | 2.42        | 2.66  |  |  |
| G   | 1.12        | 1.36  |  |  |
| Н   | 0.72        | 0.96  |  |  |
| - 1 | 4.22        | 4.98  |  |  |
| J   | 1.14        | 1.38  |  |  |
| K   | 2.20        | 2.98  |  |  |
| L   | 0.33        | 0.55  |  |  |
| М   | 2.48        | 2.98  |  |  |
| 0   | 3.70        | 3.90  |  |  |



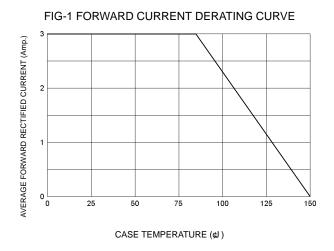
### **MAXIMUM RATINGS**

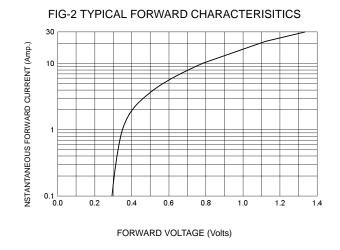
| Characteristic   | Symbol   | S06C30CE    | S06C35CE | S06C40CE | S06C45CE | Unit |
|--|--|-------------|----------|----------|----------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                       | V <sub>RRM</sub><br>V <sub>RWM</sub><br>V <sub>R</sub> | 30          | 35       | 40       | 45       | V    |
| RMS Reverse Voltage  | V <sub>R(RMS)</sub>                                    | 21          | 25       | 28       | 32       | ٧    |
| Average Rectifier Forward Current<br>Total Device (Rated V <sub>R</sub> ), T <sub>C</sub> =100¢J             | I <sub>F(AV)</sub>                                     | 3.0<br>6.0  |          |          |          | А    |
| Peak Repetitive Forward Current (Rate V <sub>R</sub> , Square Wave, 20kHz)                                   | I <sub>FM</sub>  | 6.0         |          |          |          | Α    |
| Non-Repetitive Peak Surge Current<br>(Surge applied at rate load conditions<br>halfware, single phase, 60Hz) | I <sub>FSM</sub>                                       | 100         |          |          |          | А    |
| Operating and Storage Junction<br>Temperature Range  | $T_J,T_stg$  | -65 to +150 |          |          |          | ¢ا   |

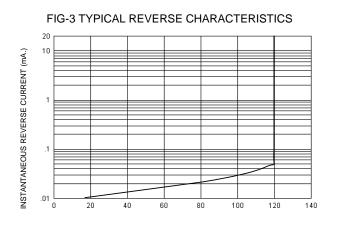
### **ELECTRIAL CHARACTERISTICS**

| Characteristic  | Symbol         | S06C30CE     | S06C35CE | S06C40CE | S06C45CE | Unit |
|---|----------------|--------------|----------|----------|----------|------|
| $\label{eq:maximum Instantaneous Forward Voltage} \begin{tabular}{l} $(I_F=3.0 \text{ Amp } T_C=25 \& I) \\ $(I_F=3.0 \text{ Amp } T_C=125 \& I) \end{tabular}$ | V <sub>F</sub> | 0.57<br>0.47 |          |          | V        |      |
| Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_C = 25 d$ ) ( Rated DC Voltage, $T_C = 125 d$ )  | I <sub>R</sub> |              | 0.<br>2  | -        |          | mA   |

# S06C30CE Thru S06C45CE







PERCENT OF RATED REVERSE VOLTAGE (4M)

